

PTRA082808NF

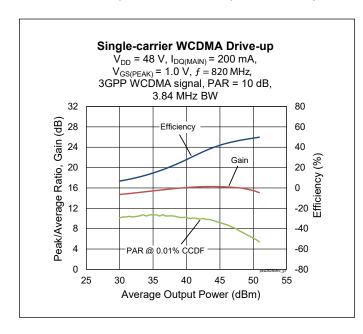
Thermally-Enhanced High Power RF LDMOS FET 280 W, 48 V, 790 – 820 MHz

Description

The PTRA082808NF is a 280-watt LDMOS FET intended for use in multi-standard cellular power amplifier applications in the 790 to 820 MHz frequency band. Features include input and output matching, high gain and thermally-enhanced package with earless flanges. Manufactured with an advanced LDMOS process, this device provides excellent thermal performance and superior reliability.



Package Types: PG-HBSOF-6-2



Features

- Broadband internal input and output matching
- · Asymmetrical design
 - Main: P_{1dB} = 115 W Typ
 - Peak: P_{1dB} = 165 W Typ
- Typical Pulsed CW performance, 820 MHz, 48 V, Doherty configuration
 - Output power at P_{3dB} = 250 W
 - Efficiency = 55.6 %
 - Gain = 16.2 dB
- Capable of handling 10:1 VSWR @ 48 V, 56.2 W (CW) output power
- Human Body Model Class 1C (per ANSI/ESDA/JEDEC JS-001)
- · Integrated ESD protection
- Low thermal resistance
- Pb-free and RoHS compliant

RF Characteristics

Single-carrier WCDMA Specifications (tested in the Doherty test fixture)

 V_{DD} = 48 V, I_{DQ} = 200 mA, $V_{GS(PEAK)}$ = 1.0 V, P_{OUT} = 56.2 W avg, f = 820 MHz, 3GPP, channel bandwidth = 3.84 MHz, peak/average = 10 dB @ 0.01% CCDF

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Gain	G _{ps}	15.2	15.5	_	dB
Drain Efficiency	η_{D}	42.7	44.5	_	%
Adjacent Channel Power Ratio	ACPR	_	-36.4	-33.5	dBc
Output PAR @ 0.01% CCDF	OPAR	6.6	7.3	_	dB

Note

All published data at T_{CASE} = 25°C unless otherwise indicated ESD: Electrostatic discharge sensitive device—observe handling precautions!





DC Characteristics (each side)

Characteristic	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Drain-Source Breakdown Voltage	V _{BR(DSS)}	105	_	_	V	$V_{GS} = 0 \text{ V}, I_{DS} = 10 \text{ mA}$	
Drain Leakage Current		_	_	1		$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}$	
Drain Leakage Current	DSS	_	_	10	μΑ	$V_{DS} = 105 \text{ V}, V_{GS} = 0 \text{ V}$	
Gate Leakage Current	I _{GSS}	_	_	1		V _{GS} = 10 V, V _{DS} = 0 V	
On-State Resistance (main)		0.07	0.3	0.66		V = 10 V V = 0.1 V	
On-State Resistance (peak)	R _{DS(on)}	0.01	0.12	0.325	Ω	$V_{GS} = 10 \text{ V}, V_{DS} = 0.1 \text{ V}$	
Operating Gate Voltage (main)	W	3.0	3.6	4.1	V	$V_{DS} = 3.6 \text{ V}, I_{DQ} = 0.2 \text{ A}$	
Operating Gate Voltage (peak)	$ V_{GS}$	_	1	_	V	V _{DS} = 1.0 V, I _{DQ} = 0 A	

Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source Voltage	V _{DSS}	105	
Gate-source Voltage	V _{GS}	-6 to +12	V
Operating Voltage	V _{DD}	0 to +55	
Junction Temperature	T _J	225	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

^{1.} Operation above the maximum values listed here may cause permanent damage. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the component. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. For reliable continuous operation, the device should be operated within the operating voltage range (V_{DD}) specified above.

2. Parameters values can be affected by end application and product usage. Values may change over time.

Thermal Characteristics

Characteristics	Symbol	Value	Unit	Conditions
Thermal Resistance (main)	D	0.766	°C/W	T _{CASE} = 70°C, 56.2 W CW
Thermal Resistance (peak)	$R_{\theta JC}$	0.208	C/W	T _{CASE} = 70°C, 200 W CW

Moisture Sensitivity Level

Level	Test Signal	Package Temperature	Unit	
3	IPC/JEDEC J-STD-020	260	°C	

Ordering Information

Type and Version	Order Code	Package Description	Shipping	
PTRA082808NF V1 R5	PTRA082808NF-V1-R5	PG-HBSOF-6-2	Tape & Reel, 500 pcs	



Typical Performance (data taken in a production test fixture)

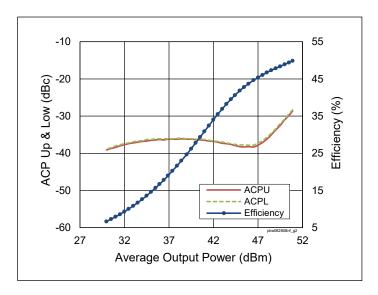


Figure 1. Single-carrier WCDMA Drive-up

$$\begin{split} &V_{DD}=48~V,~I_{DQ(MAIN)}=200~mA,\\ &V_{GS(PEAK)}=1.0~V,~f=820~MHz,\\ &3GPP~WCDMA~signal,~PAR=10~dB,\\ &BW=3.84~MHz \end{split}$$

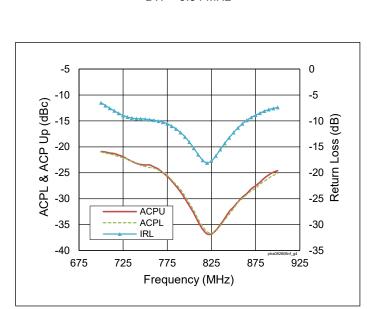


Figure 3. Single-carrier WCDMA Broadband Performance

$$\begin{split} &V_{DD}=48~V,~I_{DQ(MAIN)}=200~mA,\\ &V_{GS(PEAK)}=1.0~V,~P_{OUT}=47.5~dBm,\\ &3GPP~WCDMA~signal,~PAR=10~dB \end{split}$$

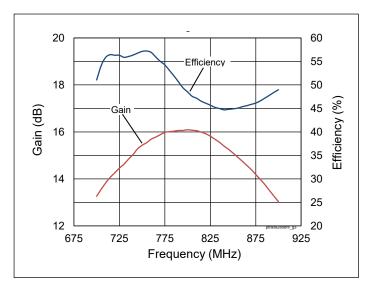


Figure 2. Single-carrier WCDMA Broadband Performance

$$\begin{split} &V_{DD}=48~V,~I_{DQ(MAIN)}=200~mA,\\ &V_{GS(PEAK)}=1.0~V,~P_{OUT}=47.5~dBm,\\ &3GPP~WCDMA~signal,~PAR=10~dB \end{split}$$

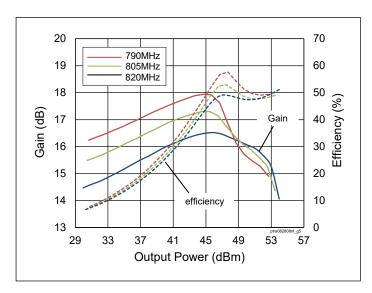


Figure 4. CW Performance

$$V_{DD} = 48 \text{ V}, \ I_{DQ(MAIN)} = 200 \text{ mA}, \\ V_{GS(PEAK)} = 1.0 \text{ V}$$



Typical Performance (cont.)

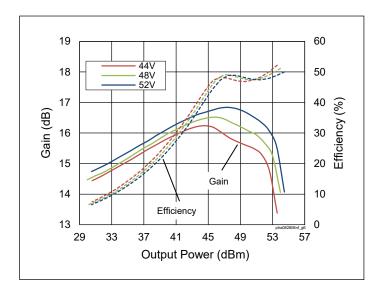


Figure 5. CW Performance at various V_{DD} $I_{DQ(MAIN)} = 200 \text{ mA}, V_{GS(PEAK)} = 1.0 \text{ V},$ f = 820 MHz

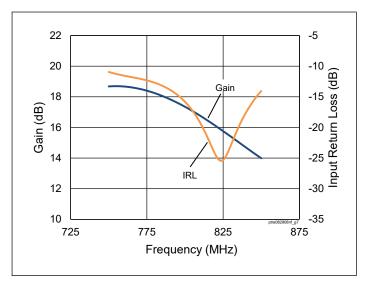


Figure 6. CW Performance Small Signal Gain & Input Return Loss

$$V_{DD} = 48 \text{ V}, \ I_{DQ(MAIN)} = 200 \text{ mA}, \\ V_{GS(PEAK)} = 1.0 \text{ V}$$



Load Pull Performance

Main Side Load Pull Performance – Pulsed CW signal: 10 μ s, 10% duty cycle, 48 V, I $_{DQ}$ = 250 mA

						P	LdB				
			Max Output Power					Max Drain Efficiency			
Freq [MHz]	Zs [Ω]	Zl [Ω]	Gain [dB]	P _{1dB} [dBm]	P _{1dB} [W]	ηD [%]	Zl [Ω]	Gain [dB]	P _{1dB} [dBm]	P _{1dB} [W]	ηD [%]
790	1.8 - j4.4	2.4 - j1.6	20.24	51.73	149	58.9	5.4+ j2.6	22.49	48.72	74	69.8
805	1.8 – j5.2	2.6 - j1.8	20.28	51.47	140	58.6	5.4+ j2.5	22.41	48.74	75	70.2
820	1.8 - j5.2	2.9 - j1.8	20.65	51.41	138	60.9	5.3+ j1.9	22.51	48.97	79	70.4

			P _{3dB}									
			Max Output Power					Max Drain Efficiency				
Freq [MHz]	Zs [Ω]	Zl [Ω]	Gain [dB]	P _{3dB} [dBm]	P _{3dB} [W]	ηD [%]	Zl [Ω]	Gain [dB]	P _{3dB} [dBm]	P _{3dB} [W]	ηD [%]	
790	1.8 – j4.4	2.6 - j1.9	18.3	52.53	179	62.7	5.5 + j0.2	20.27	50.63	116	71.2	
805	1.8 – j5.2	2.8 – j2.6	18.3	52.29	169	60.2	5.6 + j0.0	20.18	50.61	115	71.2	
820	1.8 – j5.2	2.9 – j3.1	18.4	52.24	168	60.0	5.6 + j1	20.45	50.13	103	71.3	

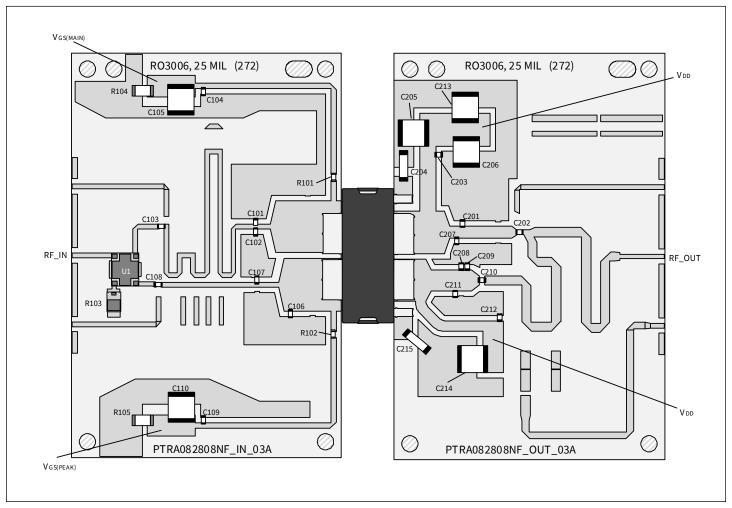
Peak Side Load Pull Performance – Pulsed CW signal: 10 μ s, 10% duty cycle, 48 V, I $_{DQ}$ = 350 mA

			P_{1dB}									
			Max Output Power					Max Drain Efficiency				
Freq [MHz]	Zs [Ω]	Zl [Ω]	Gain [dB]	P _{1dB} [dBm]	P _{1dB} [W]	ηD [%]	Zl [Ω]	Gain [dB]	P _{1dB} [dBm]	P _{1dB} [W]	ηD [%]	
790	1.5 – j4.1	1.8 – j1.3	16.26	53.30	214	60.4	3.9 + j1.2	17.03	50.89	123	72.8	
805	1.5 – j4.1	1.9 – j1.3	16.02	53.07	203	60.1	3.6 + j1.3	16.84	50.77	119	73.2	
820	1.4 – j4.6	2.0 – j1.4	16.4	53.00	200	61.0	3.1 + j2.2	16.87	50.78	120	73.0	

		P_3dB									
			Max Output Power					Max Drain Efficiency			
Freq [MHz]	Zs [Ω]	Zl [Ω]	Gain [dB]	P _{3dB} [dBm]	P _{3dB} [W]	ηD [%]	Zl [Ω]	Gain [dB]	P _{3dB} [dBm]	P _{3dB} [W]	ηD [%]
790	1.5 – j4.1	2.0 - j1.4	14.37	54.07	255	65.3	3.6 – j0.1	15.05	52.54	180	73.9
805	1.5 – j4.1	2.0 – j2.3	14.84	53.86	243	60.5	3.7 + j1.2	14.84	51.42	139	73.8
820	1.4 - j4.6	2.1 – j1.5	14.43	53.77	238	64.0	3.6 + j0.7	15.13	51.83	152	73.6



Evaluation Board, 790 - 820 MHz



Reference circuit assembly diagram (not to scale)

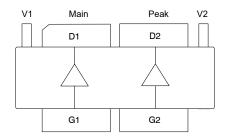
Evaluation Board Part Number	LTA/PTRA082808NF-V1
PCB Information	Rogers 3006, 0.635 mm [0.025"] thick, 2 oz. copper, $\varepsilon_r = 3.66$, $f = 790 - 820$ MHz



Components Information

Component	Description	Manufacturer	P/N	
Input				
C101, C102	Capacitor, 5.6 pF	ATC	ATC800A5R6CT250T	
C103, C104, C108, C109	Capacitor, 56 pF	ATC	ATC800A560JT250T	
C105, C110	Capacitor, 10 μF	TDK Corporation	C5750X5R1H106K230KA	
C106	Capacitor, 10 pF	ATC	ATC800A100JT250T	
C107	Capacitor, 1.5 pF	ATC	ATC800A1R5CT250T	
R101, R102	Resistor, 10 ohms	Panasonic Electronic Components	ERJ-8GEYJ100V	
R103	Resistor, 50 ohms	Anaren	C8A50Z4A	
R104, R105	Resistor, 1000 ohms	Panasonic Electronic Components	ERJ-8GEYJ102V	
U1	Hybrid Coupler	Anaren	X3C07P1-05S	
Output				
C201	Capacitor, 3.0 pF	ATC	ATC800A3R0CT250T	
C202	Capacitor, 15 pF	ATC	ATC800A150JT250T	
C203, C210, C212	Capacitor, 82 pF	ATC	ATC800A820JT250T	
C204, C205, C206, C213, C214, C215	Capacitor, 10 μF , 100V	TDK Corporation	C5750X7S2A106M230KB	
C207	Capacitor, 6.8 pF	ATC	ATC800A6R8CT250T	
C208	Capacitor, 3.9 pF	ATC	ATC800A3R9CT250T	
C209	Capacitor, 2.2 pF	ATC	ATC800A2R2CT250T	
C211 Capacitor, 10 pF		ATC	ATC800A100JT250T	

Pinout Diagram (top view)



Pin	Description
D1	Drain Device 1 (Main)
D2	Drain Device 2 (Peak)
G1	Gate Device 1 (Main)
G2	Gate Device 2 (Peak)
S	Source (flange)
V1, V2	Drain video decoupling, no DC bias



Package Outline Specifications - Package PG-HBSOF-6-2 (top view)

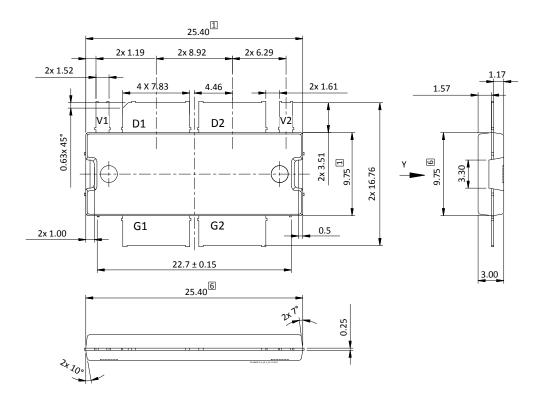


Diagram Notes—unless otherwise specified:

- 1. Mold/dam bar/metal protrusion of 0.30 mm max per side not included.
- 2. Metal protrusions are connected to source and shall not exceed 0.10 mm max.
- 3. Fillets and radii: all radii are 0.3 mm max.
- 4. Interpret dimensions and tolerances per ISO 8015.
- 5. Dimensions are mm.
- 6. Does not include mold/dam bar and metal protrusion.
- 7. Exposed metal surface is tin-plated, may not be covered by mold compound.
- 8. All tolerances \pm 0.1 mm unless specified otherwise.
- 9. All metal surfaces are tin-plated, except area of cut.
- 10. Lead thickness: 0.25 mm.
- 11. Pins: D1, D2 = drain; G1, G2 = gate; V1, V2 = drain video decoupling, no DC bias



Package Outline Specifications (cont.) - Package PG-HBSOF-6-2 (bottom view)

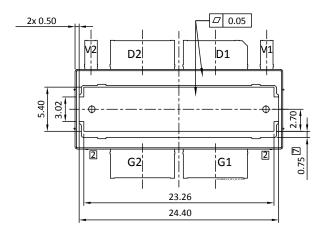


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- 1. Mold/dam bar/metal protrusion of 0.30 mm max per side not included.
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- 3. Fillets and radii: all radii are 0.3 mm max.
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- 5. Dimensions are mm.
- 6. Does not include mold/dam bar and metal protrusion.
- 7. Exposed metal surface is tin-plated, may not be covered by mold compound.
- 8. All tolerances \pm 0.1 mm unless specified otherwise.
- 9. All metal surfaces are tin-plated, except area of cut.
- 10. Lead thickness: 0.25 mm.
- 11. Pins: D1, D2 = drain; G1, G2 = gate; V1, V2 = drain video decoupling, no DC bias



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